Product data sheet

1 General description

The BTS7203U is a dual channel Receiver Analog Front-End module (RX AFE) available in a leadframe HVQFN package.

The BTS7203U is designed for 5G mMIMO Infrastructure applications. The BTS7203U includes 2 independent receive channels with a low noise amplifier (LNA) with variable gain control. Each channel also has a switch for high-power TX signals.

The device is matched to 50 Ω and integrates harmonic and out-of-band filtering which minimizes the layout area in the application.

2 Features and benefits

- Operating frequency range 3.3 GHz 4.2 GHz
- 170 mW power dissipation per channel
- RX power gain 36 dB
- RX power gain attenuation step 6 dB
- Typical Noise Figure 1.3 dB
- High TX power handling 37 dBm (9 dB PAPR)
- Single-ended input /output RF ports matched to 50 Ω
- Fast switching time between operation modes
- ESD protection on all pins
- Leadframe HVQFN package 5.0 mm x 5.0 mm x 0.85 mm with 32 pins

3 Applications

- 5G mMIMO
- · Wireless Infrastructure



3.3 GHz - 4.2 GHz RX Analog Front-End IC

Quick reference data

Table 1. Quick reference data

f = 3.75 GHz; V_{CC} = 3.3 V, T_{case} = 50 °C; input and output 50 Ω ; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
High gai	in RX mode; signal from ANT to I	RX_OUT				
I _{CC}	supply current		-	51	57	mA
Gp	power gain		34.5	36	37.5	dB
NF	noise figure		-	1.3	1.4	dB
IP3 _o	output third-order intercept point	2-tones at 10 MHz distance, P _i = -40 dBm each tone	20	23	-	dBm
P _{i(1dB)}	input power at 1 dB gain compression		-25	-24	-	dBm
Low gai	n RX mode; signal from ANT to F	X_OUT				
I _{CC}	supply current		-	51	57	mA
G _p	power gain		28.5	30	31.5	dB
a _{step}	attenuation step		5.3	6	6.4	dB
NF	noise figure		-	1.5	1.6	dB
IP3 _o	output third-order intercept point	2-tones at 10 MHz distance, P _i = -40 dBm each tone	-	22	-	dBm
P _{i(1dB)}	input power at 1 dB gain compression		-19	-18	-	dBm
TX mode	e; signal from ANT to TERM				'	
I _{CC}	supply current		-	5.9	6.5	mA
P _{i(AV)TX} maximum average input power in	applied on ANT pin, 10 years, T _{case(AV)} = 99 °C [2]	34	-	-	dBm	
	TX mode ^[1]	applied on ANT pin, 10 seconds, T _{case} = 105 °C [3]	37	-	-	dBm

CP-OFDM with 9 dB PAPR, BW = 100 MHz, QPSK modulated, SCS = 60 kHz, fully allocated

Ordering information

Table 2. Ordering information

Type number	Orderable part	Package				
number		Name	Description	Version		
BTS7203U	BTS7203UHP	HVQFN32	Plastic thermal enhanced very thin quad flat package; no leads; 32 terminals; body 5.0 mm x 5.0 mm x 0.85 mm	SOT617-3		

Marking

Table 3. Marking

Type number	Marking code
BTS7203U	7203U

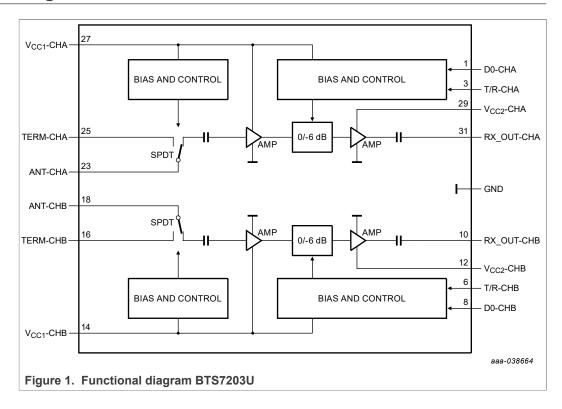
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T_{case(AV)} is an equivalent temperature that yields the same aging over life time as the expected temperature profile which includes temperatures up to 105 °C See <u>Table 7</u>

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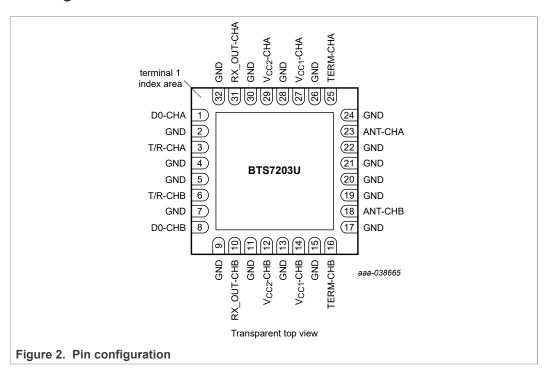
7 Functional diagram



3.3 GHz - 4.2 GHz RX Analog Front-End IC

8 Pinning information

8.1 Pin diagram



8.2 Pin description

Table 4.

Pin	Symbol	Description
1	D0-CHA	Select attenuation for channel A
2, 4, 5, 7, 9, 11, 13, 15, 17, 19, 20, 21, 22, 24, 26, 28, 30, and 32	GND	Ground reference
3	T/R-CHA	Select RX mode / TX mode for channel A
6	T/R-CHB	Select RX mode / TX mode for channel B
8	D0-CHB	Select attenuation for channel B
10	RX_OUT-CHB	RF output for channel B (50 Ω , single ended)
12, 14	V _{CC} -CHB	Supply voltage for channel B
16	TERM-CHB	Termination RF output for channel B (50 Ω , single ended, DC at 0 V)
18	ANT-CHB	RF input for channel B (50 Ω , single ended, DC at 0 V)
23	ANT-CHA	RF input for channel A (50 Ω , single ended, DC at 0 V)
25	TERM-CHA	Termination RF output for channel A (50 Ω , single ended, DC at 0 V)
27, 29	V _{CC} -CHA	Supply voltage for channel A
31	RX_OUT-CHA	RF output for channel A (50 Ω , single ended)
Die paddle	GND	Ground reference

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9 Functional description

9.1 Modes of operation

Table 5. Modes of operation for channel A

T/R-CHA	D0-CHA	Mode of Operation
Low	Low	RX High gain mode for channel A
Low	High	RX 6 dB reduced-gain mode for channel A
High	Low/High	TX mode for channel A

Table 6. Modes of operation for channel B

T/R-CHB	D0-CHB	Mode of Operation
Low	Low	RX High gain mode for channel B
Low	High	RX 6 dB reduced-gain mode for channel B
High	Low/High	TX mode for channel B

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10 Limiting values

Table 7. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134)

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.3	6	V
VDC _(ctrl_pins)	DC voltage on control pins	applied on control pins D0 and T/R	-0.3	3.45	V
VDC _(RF_pins)	DC voltage on RF pins	applied on both ANT, and both TERM, RF pins	0	0	V
P _{i(AV)RX}	average input power in RX mode ^[1]	applied on ANT pin, 24 hours, T _{case} = 105 °C	-	11	dBm
P _{i(AV)TX}	average input power in TX mode [1]	applied on ANT pin, 10 seconds, T _{case} = 105 °C	37	39	dBm
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	150	°C
V _{ESD}	electrostatic discharge voltage	Human Body Model (HBM) according to ANSI/ESDA/JEDEC standard JS-001	-2	2	kV
		Charged Device Model (CDM) according to ANSI/ESDA/JEDEC standard JS-002	-500	500	V

^[1] CP-OFDM with 9 dB PAPR, BW = 100 MHz, QPSK modulated, SCS = 60 kHz, fully allocated

11 Recommended operating conditions

Table 8. Recommended operating conditions

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
f _{oper}	operating frequency			3.3	-	4.2	GHz
Z_0	characteristic impedance			-	50	-	Ω
V _{CC}	supply voltage	on pins V_{CC1} , and V_{CC2}	[1]	3.15	3.3	3.45	V
V _{IH}	HIGH-level input voltage	at pins D0, and T/R		1.2	1.8	2.5	V
V_{IL}	LOW-level input voltage	at pins D0, and T/R		0	-	0.6	V
T _{case}	case temperature	exposed die paddle at package bottom	,	-40	50	105	°C

^[1] channel A and channel B can be used independently

12 Thermal characteristics

Table 9. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-case)}	channel-junction to case thermal resistance	TX mode	-	49	-	K/W
		RX mode	-	55	-	K/W

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13 Characteristics

Table 10. Characteristics

f = 3.75 GHz; V_{CC} = 3.3 V, T_{case} = 50 °C; input and output 50 Ω ; unless otherwise specified. Characteristics apply to each channel A and B separately.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
High gain R	K mode; signal from ANT to RX_C	DUT				
I _{cc}	supply current		-	51	57	mA
Gp	power gain		34.5	36	37.5	dB
		f = 3.3 GHz to 4.2 GHz, T_{case} = -40 °C to 105 °C	33.5	-	39	dB
G _{flat}	gain flatness	in 200 MHz band	-	-	0.5	dB
NF noise figure			-	1.3	1.4	dB
		f = 3.3 GHz to 4.2 GHz, T_{case} = -40 °C to 105 °C	-	-	1.7	dB
RLi	input return loss	f = 3.3 GHz to 4.2 GHz		17	-	dB
RL_o	output return loss	f = 3.3 GHz to 4.2 GHz	12	17	-	dB
RL _{align(RX-TX)}	return loss alignment RX-TX	R_{TERM} = 50 Ω , f = 3.3 GHz to 4.2 GHz	12	-	-	dB
α _{isol(ch-ch)}	isolation channel to channel	f = 3.3 GHz to 4.2 GHz [1]	40	42	-	dB
G _{rel(f2/f0)}	relative gain (G _{f2} /G _{f0})	$f_0 = 3.3 \text{ GHz to } 4.2 \text{ GHz}, f_2 = 2 \text{ x } f_0$	-	-35	-25	dB
G _{rel(f3/f0)}	relative gain (G _{f3} /G _{f0})	$f_0 = 3.3 \text{ GHz to } 4.2 \text{ GHz}, f_3 = 3 \text{ x } f_0$	-	-50	-45	dB
α _{2Ho}	output second harmonic level	P _o = 0 dBm	-	-56	-40	dBm
α _{3Ho}	output third harmonic level	$P_o = 0 \text{ dBm}$		-69	-58	dBm
IP3 _o	output third-order intercept point	2-tones at 10 MHz distance, P _i = -40 dBm each tone	20	23	-	dBm
		2-tones at 10 MHz distance, P_i = -40 dBm each tone, f_0 = 3.3 GHz to 4.2 GHz, T_{case} = -40 °C to 105 °C	18	-	_	dBm
P _{i(1dB)}	input power at 1 dB gain compression		-25	-24	-	dBm
K	stability factor	1 MHz to 20 GHz, T _{case} = -40 °C to 105 °C	1	-	-	-
Low gain RX	mode; signal from ANT to RX_O	UT				
I _{cc}	supply current		-	51	57	mA
Gp	power gain		28.5	30	31.5	dB
		f = 3.3 GHz to 4.2 GHz, T _{case} = -40 °C to 105 °C	27.5	-	33	dB
α_{step}	attenuation step		5.3	6	6.4	dB
G _{flat}	gain flatness	in 200 MHz band	-	-	1.55	dB
NF	noise figure		-	1.5	1.6	dB
		f = 3.3 GHz to 4.2 GHz, T _{case} = -40 °C to 105 °C	-	-	2.3	dB
RLi	input return loss	f = 3.3 GHz to 4.2 GHz		17	-	dB
RLo	output return loss	f = 3.3 GHz to 4.2 GHz	12	17	-	dB
RL _{align(RX-TX)}	return loss alignment RX-TX	R_{TERM} = 50 Ω , f = 3.3 GHz to 4.2 GHz	12	-	-	dB

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Table 10. Characteristics...continued

f = 3.75 GHz; V_{CC} = 3.3 V, T_{case} = 50 °C; input and output 50 Ω ; unless otherwise specified. Characteristics apply to each channel A and B separately.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
α _{isol(ch-ch)}	isolation channel to channel	f = 3.3 GHz to 4.2 GHz [1]	40	42	-	dB
G _{rel(f2/f0)}	relative gain (G _{f2} /G _{f0})	$f_0 = 3.3 \text{ GHz to } 4.2 \text{ GHz}, f_2 = 2 \text{ x } f_0$	-	-35	-25	dB
G _{rel(f3/f0)}	relative gain (G _{f3} /G _{f0})	$f_0 = 3.3 \text{ GHz to } 4.2 \text{ GHz}, f_3 = 3 \text{ x } f_0$	-	-50	-45	dB
α _{2Ho}	output second harmonic level	$P_o = 0 \text{ dBm}$	-	-56	-45	dBm
α _{3Ho}	output third harmonic level	$P_0 = 0 \text{ dBm}$	-	-65	-55	dBm
IP3 _o	output third-order intercept point	2-tones at 10 MHz distance, P _i = -40 dBm each tone	20	22	-	dBm
		2-tones at 10 MHz distance, P _i = -40 dBm each tone, f ₀ = 3.3 GHz to 4.2 GHz, T _{case} = -40 °C to 105 °C	17	-	-	dBm
P _{i(1dB)}	input power at 1 dB gain compression		-19	-18	-	dBm
K	stability factor	1 MHz to 20 GHz, T _{case} = -40 °C to 105 °C	1	-	-	-
TX mode; si	gnal from ANT to TERM		J			
I _{cc}	supply current		-	5.9	6.5	mA
IL	insertion loss	from ANT to TERM	-	0.55	0.6	dB
RLi	input return loss	f = 3.3 GHz to 4.2 GHz	12	22	-	dB
RLo	output return loss	f = 3.3 GHz to 4.2 GHz	12	22	-	dB
α _{isol(ANT-RX)}	isolation between ANT to RX_OUT	f = 3.3 GHz to 4.2 GHz	55	-	-	dB
$P_{i(AV)TX}$	Maximum average input power in TX mode ^[2]	applied on ANT pin, lifetime (10 yrs), T _{case(AV)} = 99 °C	34	-	-	dBm
Switching b	etween modes					
$t_{sw(\alpha)RX}$	switching time RX attenuation		-	-	100	ns
t _{sw(RX-TX)}	switching from RX to TX	for the power transient at RX_OUT		-	0.5	μs
t _{sw(TX-RX)}	switching from TX to RX		-	-	1	μs

G, [ANT-CHA, RX_OUT-CHA] / Gp [ANT-CHB, RX_OUT-CHA] CP-OFDM with 9 dB PAPR, BW = 100 MHz, QPSK modulated, SCS = 60 kHz, fully allocated [2] [3]

T_{case(AV)} is an equivalent temperature that yields the same aging over life time as the expected temperature profile which includes temperatures up to 105 °C

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14 Graphs

14.1 All modes

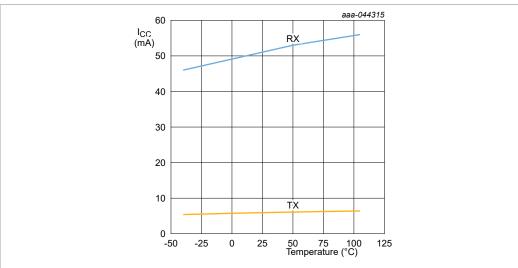


Figure 3. DC supply current versus temperature of a single channel

- $(1) = RX \mod e$
- (2) = TX mode

14.2 High gain RX mode

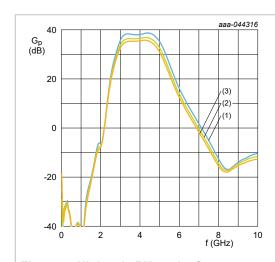


Figure 4. High gain RX mode, $\boldsymbol{G}_{\boldsymbol{p}}$ versus frequency over temperature



(2)
$$T_{case} = 50 \, ^{\circ}C$$

(3)
$$T_{case} = 105 \, ^{\circ}C$$

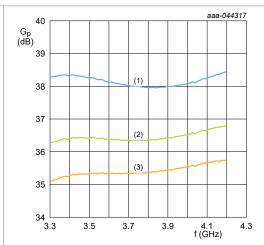


Figure 5. High gain RX mode, $\mathbf{G}_{\mathbf{p}}$ versus frequency over temperature

(1)
$$T_{case} = -40 \, ^{\circ}C$$

(2)
$$T_{case} = 50 \, ^{\circ}C$$

(3)
$$T_{case}$$
 = 105 °C

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(1)

⁽²⁾

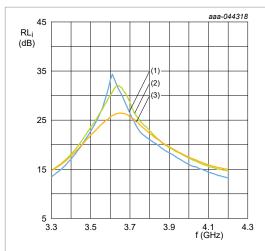
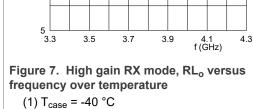


Figure 6. High gain RX mode, RL_i versus frequency over temperature



(2)
$$T_{case} = 50 \, ^{\circ}C$$

(3)
$$T_{case}$$
 = 105 °C





45 RL_o (dB)

35

25

(3)
$$T_{case} = 105 \, ^{\circ}C$$

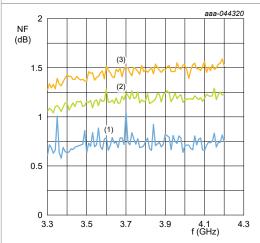


Figure 8. High gain RX mode, NF versus frequency over temperature



(2)
$$T_{case} = 50 \, ^{\circ}C$$

(3)
$$T_{case} = 105 \, ^{\circ}C$$

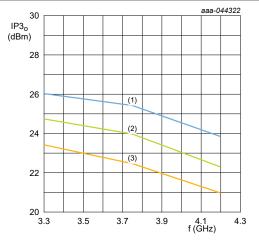


Figure 9. High gain RX mode, IP3_o versus frequency over temperature

- (1) $T_{case} = -40 \, ^{\circ}C$
- (2) $T_{case} = 50 \, ^{\circ}C$
- (3) T_{case} = 105 °C

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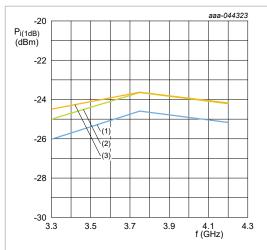


Figure 10. High gain RX mode, $P_{i(1dB)}\,\mbox{versus}$ frequency over temperature



(2)
$$T_{case} = 50 \, ^{\circ}C$$

(3)
$$T_{case} = 105 \, ^{\circ}C$$

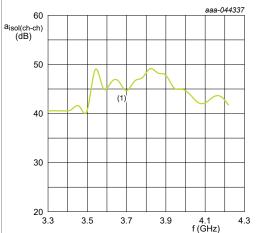


Figure 11. High gain RX mode, Channel Isolation versus frequency

(1)
$$T_{case} = 50 \, ^{\circ}C$$

14.3 Low gain RX mode

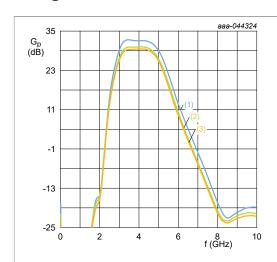


Figure 12. Low gain RX mode, G_p versus frequency over temperature

(1)
$$T_{case} = -40 \, ^{\circ}C$$

(2)
$$T_{case} = 50 \, ^{\circ}C$$

(3)
$$T_{case} = 105 \, ^{\circ}C$$

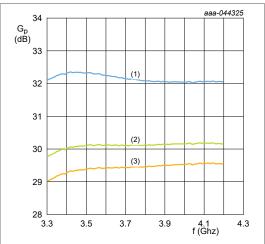


Figure 13. Low gain RX mode, G_p versus frequency over temperature

(1)
$$T_{case} = -40 \, ^{\circ}C$$

(2)
$$T_{case} = 50 \, ^{\circ}C$$

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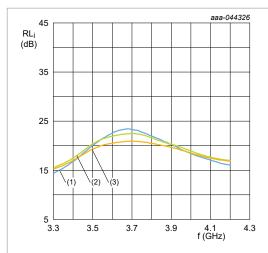
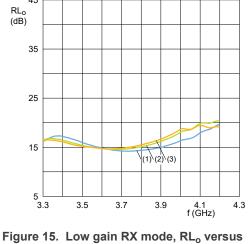


Figure 14. Low gain RX mode, RLi versus frequency over temperature



(2)
$$T_{case} = 50 \, ^{\circ}C$$

(3)
$$T_{case} = 105 \, ^{\circ}C$$



frequency over temperature

(1)
$$T_{case} = -40$$
 °C

45

(2)
$$T_{case} = 50 \, ^{\circ}C$$

(3)
$$T_{case} = 105 \, ^{\circ}C$$

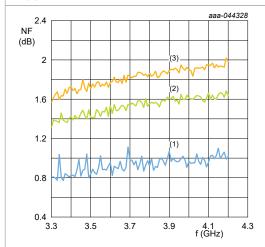


Figure 16. Low gain RX mode, NF versus frequency over temperature



(2)
$$T_{case} = 50 \, ^{\circ}C$$

(3)
$$T_{case}$$
 = 105 °C

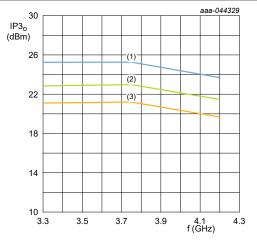


Figure 17. Low gain RX mode, IP3o versus frequency over temperature

(1)
$$T_{case} = -40 \, ^{\circ}C$$

(2)
$$T_{case} = 50 \, ^{\circ}C$$

(3)
$$T_{case} = 105 \, ^{\circ}C$$

3.3 GHz - 4.2 GHz RX Analog Front-End IC

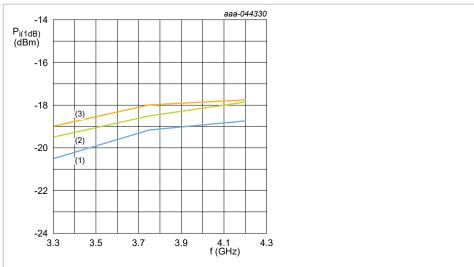


Figure 18. Low gain RX mode, Input $P_{i(1dB)}$ versus frequency over temperature

- (1) $T_{case} = -40 \, ^{\circ}C$
- (2) $T_{case} = 50 \, ^{\circ}C$
- (3) $T_{case} = 105 \, ^{\circ}C$

14.4 TX mode

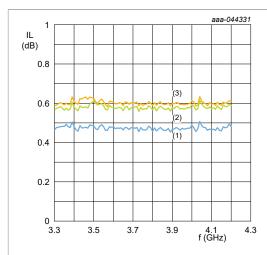


Figure 19. TX mode, α_{ins} versus frequency over temperature



(2)
$$T_{case} = 50 \, ^{\circ}C$$

(3)
$$T_{case} = 105 \, ^{\circ}C$$

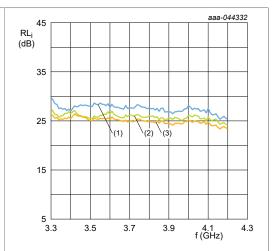


Figure 20. TX mode, RL_i versus frequency over temperature

- (1) $T_{case} = -40 \, ^{\circ}C$
- (2) $T_{case} = 50 \, ^{\circ}C$
- (3) T_{case} = 105 °C

3.3 GHz - 4.2 GHz RX Analog Front-End IC

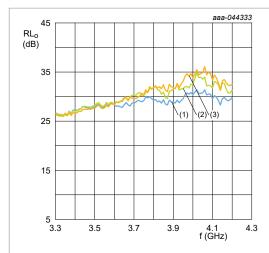


Figure 21. TX mode, RL_o versus frequency over temperature

- (1) T_{case} = -40 °C
- (2) $T_{case} = 50 \, ^{\circ}C$
- (3) $T_{case} = 105 \, ^{\circ}C$

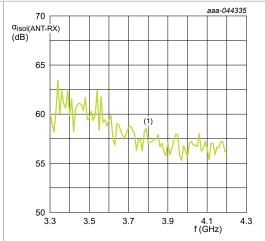


Figure 22. TX mode, ANT to RX_OUT isolation versus frequency

$$(1) = 50 \, ^{\circ}\text{C}$$

3.3 GHz - 4.2 GHz RX Analog Front-End IC

15 Application information

Table 11. Application schematic

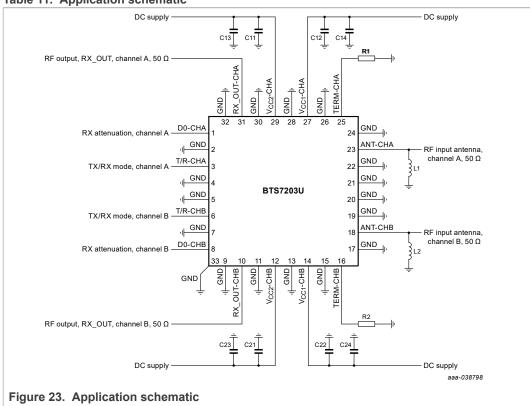
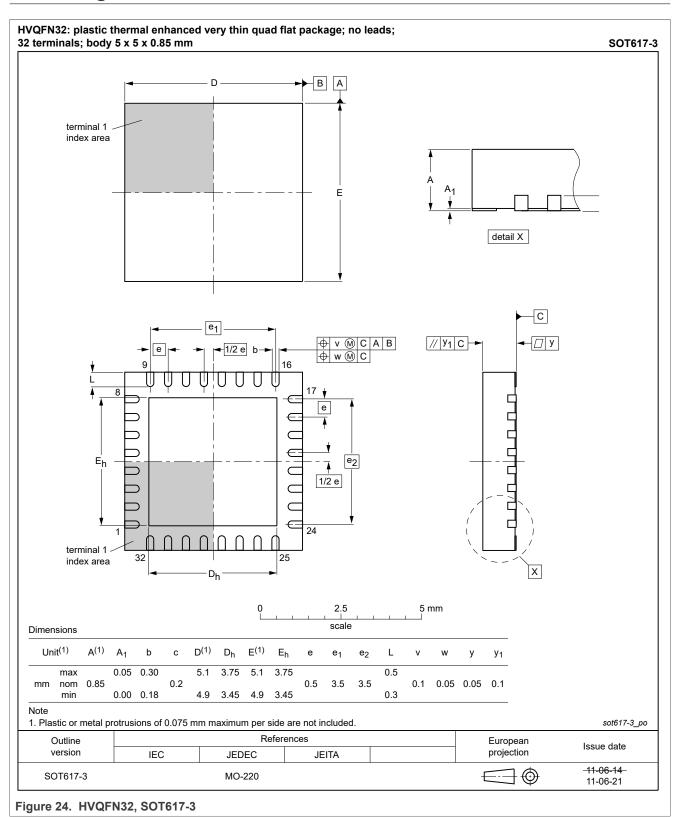


Table 12. List of components

Component	Description	Value	amount	Remarks
R1, and R2	load resistor	50 Ω, 50 W	2	must be able to withstand 34 dBm average power over lifetime
C11, C12, C21, and C22	capacitor	10 nF	4	as close as possible, less than 10 mm from IC
C13, C14, C23, and C24	capacitor	1 μF	4	as close as possible, less than 10 mm from IC
L1, and L2	inductor	120 nH	2	high-Q inductor, close to IC. Inductor is recommended to improve the switching time with a low ohmic connection at the ANT port.

3.3 GHz - 4.2 GHz RX Analog Front-End IC

16 Package outline



3.3 GHz - 4.2 GHz RX Analog Front-End IC

16.1 Footprint and solder information

NXP recommends by default to apply the soldering and footprint guidelines as are released in POD SOT617-3.

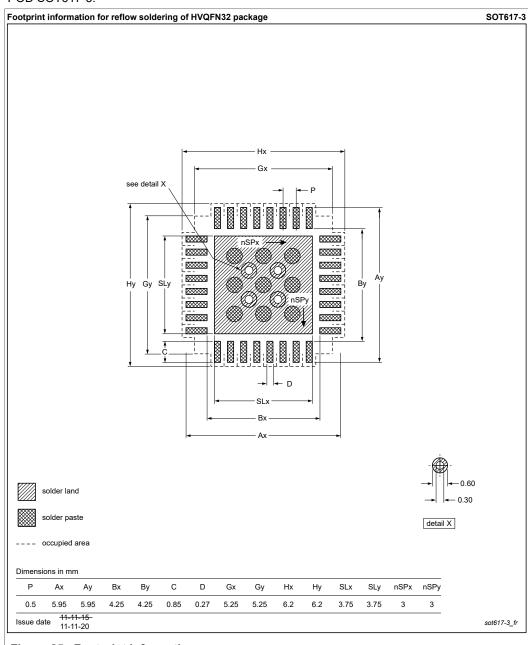


Figure 25. Footprint information

3.3 GHz - 4.2 GHz RX Analog Front-End IC

17 Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices. Such precautions are described in the *ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A* or equivalent standards.

18 Abbreviations

Table 13. Abbreviations

Table 13. Abbreviations			
Acronym	Description		
AMP	amplifier		
ANT	antenna		
CP-OFDM	cyclic prefix orthogonal frequency division multiplexing		
D0	data line 0		
ESD	electrostatic discharge		
HVQFN	heat sink very thin quad flat no-leads		
LNA	low noise amplifier		
mMIMO	massive multiple-input multiple-output		
PAPR	peak to average power ratio		
QPSK	quadrature phase shift keying		
SCS	sub carrier spacing		
SPDT	single pull double throw		
TERM	termination		
T/R	transmit/receive mode		

19 Revision history

Table 14. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BTS7203U v.6.1	20211029	Product data sheet	-	BTS7203U v.6
modification	added "IC" to the title like in the other related products			
BTS7203U v.6	20211026	Product data sheet	-	BTS7203U v.5
modification	 adapted some characteristic values added graphs changed status to Product data sheet added description on 120 nH coil 			
BTS7203U v.5	20211013	Objective data sheet	-	BTS7203U v.4

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Table 14. Revision history...continued

Document ID	Release date	Data sheet status	Change notice	Supersedes	
modification	 changed footnote at α_{isol(ch-ch)} for both RX modes added value for Thermal resistance added parameter insertion loss to the TX mode characteristics table corrected the orderable part number added frequency setting to the Gp condition on both RX gain modes changed values on some parameters 				
BTS7203U v.4	20210624	Objective data sheet	-	BTS7203U v.3.1	
modification	 updated the inductor value in the table List of components from 20 nH to 120 nH added P_{i(AV)TX} parameter to the TX Characteristics table Corrected the Typical, and Maximum value on the RX I_{CC} changed footnote at α_{isol(ch-ch)} for both RX modes added value for Thermal resistance added parameter insertion loss to the TX mode characteristics table corrected the orderable part number 				
BTS7203U v.3.1	20210430	Objective data sheet	-	BTS7203U v.3	
modification	removed condi	• removed condition on lifetime, and footnote on parameter P _{i(AV)TX} at Limiting values			
BTS7203U v.3	20210409	Objective data sheet	-	BTS7203U v.2.3	
modification	changed Typica	al, and Max values on so	me parameters		
BTS7203U v.2.3	20210317	Objective data sheet	-	BTS7203U v.2.2	
modification	 changed T_{case} from 50 °C to 105 °C for P_{i(AV)RX} at Limiting values added footnote to parameter P_{i(AV)TX} at Limiting values 				
BTS7203U v.2.2	20210311	Objective data sheet	-	BTS7203U v.2.1	
modification	 adapted the Modes of operation tables removed and adapted Switching mode conditions adapted the conditions on some parameters 				
BTS7203U v.2.1	20210224	Objective data sheet	-	BTS7203U v.2	
modification	updated condit	ions on characteristics		.	
BTS7203U v.2	20200903	Objective data sheet	-	BTS7203U v.1	
modification	 updated the list with parameters on characteristics added extra conditions on some parameters Added and changed some Min, Typ, and Max values changed the remark on the R1, and R2 in the list of application components 				
BTS7203U v.1	20200827	Objective data sheet	_	-	

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20 Legal information

20.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions".
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